

TECHNICAL DATA
 DATA SHEET 629, REV. A

HERMETIC POWER SCHOTTKY RECTIFIER
Ultra Low Reverse Leakage
200°C Operating Temperature

DESCRIPTION: 100 VOLT, 15 AMP, POWER SCHOTTKY RECTIFIER IN A SHD-1/1A/1B PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_C = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	100	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C=100^\circ\text{C}$)	I_O	15	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT ($t=8.3\text{ms}$, Sine)	I_{FSM}	280	Amps
MAXIMUM JUNCTION CAPACITANCE ($V_f=5\text{V}$)	C_T	500	pF
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R_{\theta JC}$	0.85	$^\circ\text{C/W}$
MAXIMUM OPERATING TEMPERATURE RANGE	T_{op}	-65 to + 200	$^\circ\text{C}$
MAXIMUM STORAGE TEMPERATURE RANGE	T_{stg}	-65 to + 175	$^\circ\text{C}$

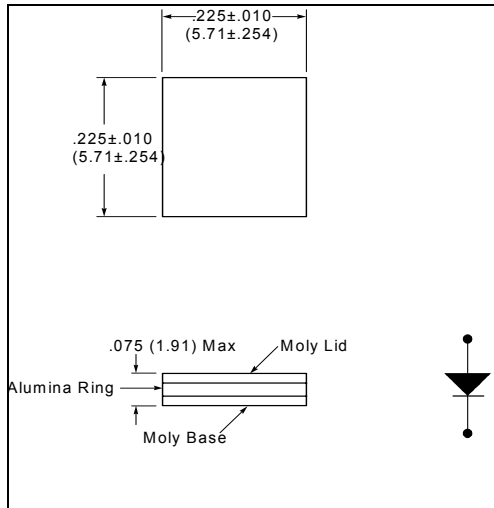
ELECTRICAL CHARACTERISTICS

CHARACTERISTIC			
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 15$ Amps) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	V_f	.84 .68	Volts
MAXIMUM REVERSE CURRENT (I_r @ 100V PIV) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	I_r	.01 1.0	mA

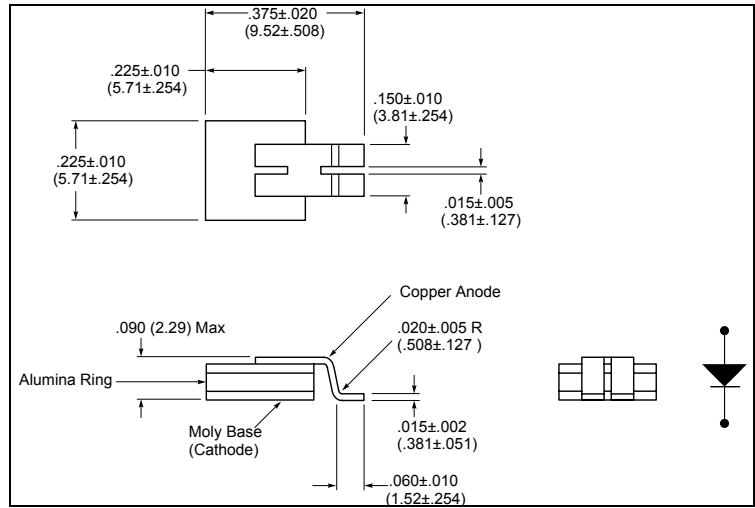
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MECHANICAL DIMENSIONS: In Inches / mm

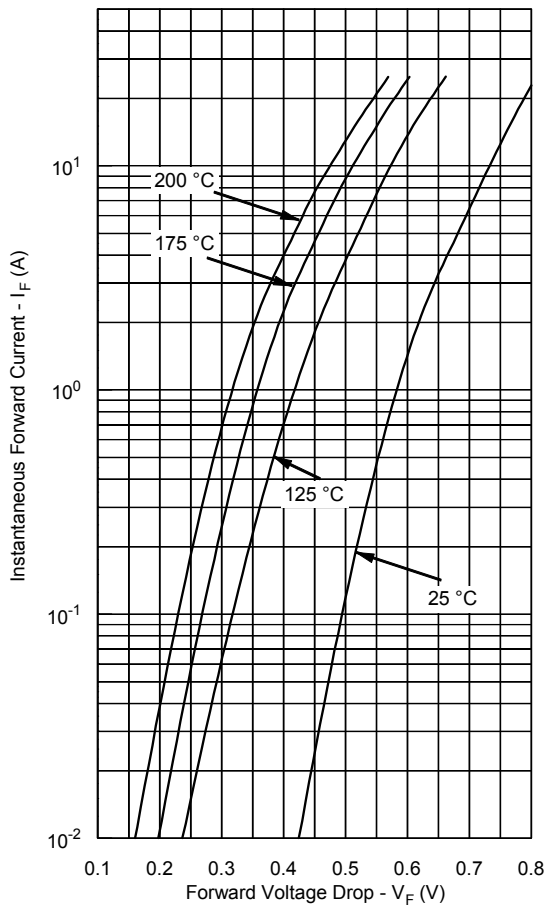
SHD-1



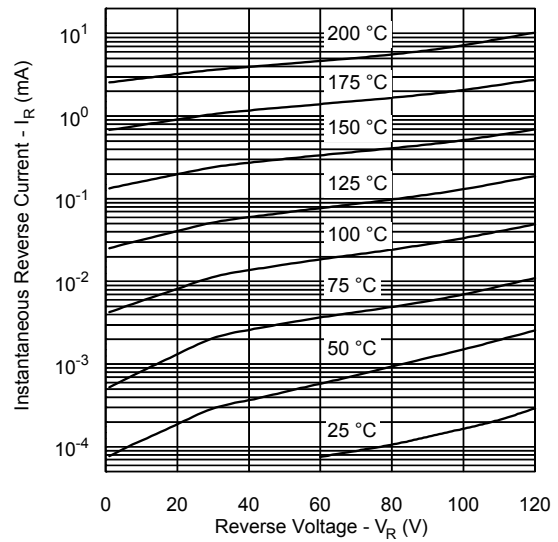
SHD-1B



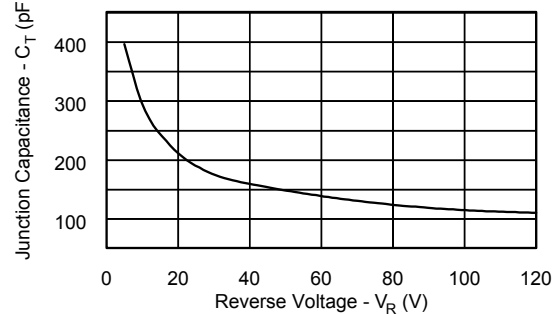
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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